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Team Nexperia

NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 4.7 k $\Omega$ 

Rev. 10 — 8 December 2011

**Product data sheet** 

### 1. Product profile

### 1.1 General description

NPN Resistor-Equipped Transistor (RET) family in Surface-Mounted Device (SMD) plastic packages.

#### Table 1. Product overview

Type number	Package	•		PNP	Package	
	NXP	JEITA	JEDEC	complement	configuration	
PDTC143EE	SOT416	SC-75	-	PDTA143EE	ultra small	
PDTC143EM	SOT883	SC-101	-	PDTA143EM	leadless ultra small	
PDTC143ET	SOT23	-	TO-236AB	PDTA143ET	small	
PDTC143EU	SOT323	SC-70	-	PDTA143EU	very small	

### 1.2 Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design

#### **1.3 Applications**

- Digital applications in automotive and industrial segments
- Control of IC inputs

- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified
- Cost-saving alternative for BC847/857 series in digital applications
- Switching loads

#### 1.4 Quick reference data

#### Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base	-	-	50	V
lo	output current		-	-	100	mA
R1	bias resistor 1 (input)		3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio		0.8	1	1.2	



### NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 4.7 k $\Omega$

#### **Pinning information** 2.

Pin	Description	Simplified outline	Graphic symbol
SOT23; S	OT323; SOT416		
1	input (base)	_	
2	GND (emitter)	3	
3	output (collector)	1 2 006aaa144	1 R1 R2 sym007
SOT883			
1	input (base)		
2	GND (emitter)		
3	output (collector)	2 Transparent top view	1 R1 R2 sym007

### 3. Ordering information

Type number	Package	Package					
	Name	Description	Version				
PDTC143EE	SC-75	plastic surface-mounted package; 3 leads	SOT416				
PDTC143EM	SC-101	leadless ultra small plastic package; 3 solder lands; body 1.0 $\times$ 0.6 $\times$ 0.5 mm	SOT883				
PDTC143ET	-	plastic surface-mounted package; 3 leads	SOT23				
PDTC143EU	SC-70	plastic surface-mounted package; 3 leads	SOT323				

#### Marking 4.

Table 5. Marking codes	
Type number	Marking code <sup>[1]</sup>
PDTC143EE	02
PDTC143EM	E1
PDTC143ET	*02
PDTC143EU	*02

[1] \* = placeholder for manufacturing site code

#### PDTC143E\_SER **Product data sheet**

#### NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 4.7 k $\Omega$

### 5. Limiting values

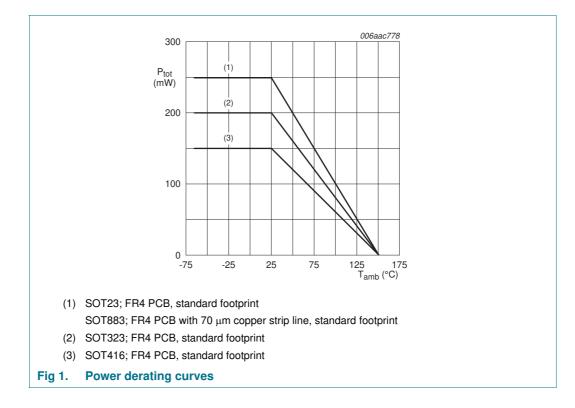
Symbol	Parameter	Conditions	Min	Мах	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter	-	50	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	50	V
V <sub>EBO</sub>	emitter-base voltage	open collector	-	10	V
VI	input voltage				
	positive		-	+30	V
	negative		-	-10	V
lo	output current		-	100	mA
I <sub>CM</sub>	peak collector current	single pulse; $t_p \leq 1 ms$	-	100	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$			
	PDTC143EE (SOT416)		[1][2] _	150	mW
	PDTC143EM (SOT883)		[2][3]	250	mW
	PDTC143ET (SOT23)		[1] -	250	mW
	PDTC143EU (SOT323)		[1] -	200	mW
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

[3] Device mounted on an FR4 PCB with 70 µm copper strip line, standard footprint.

#### NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 4.7 k $\Omega$



### 6. Thermal characteristics

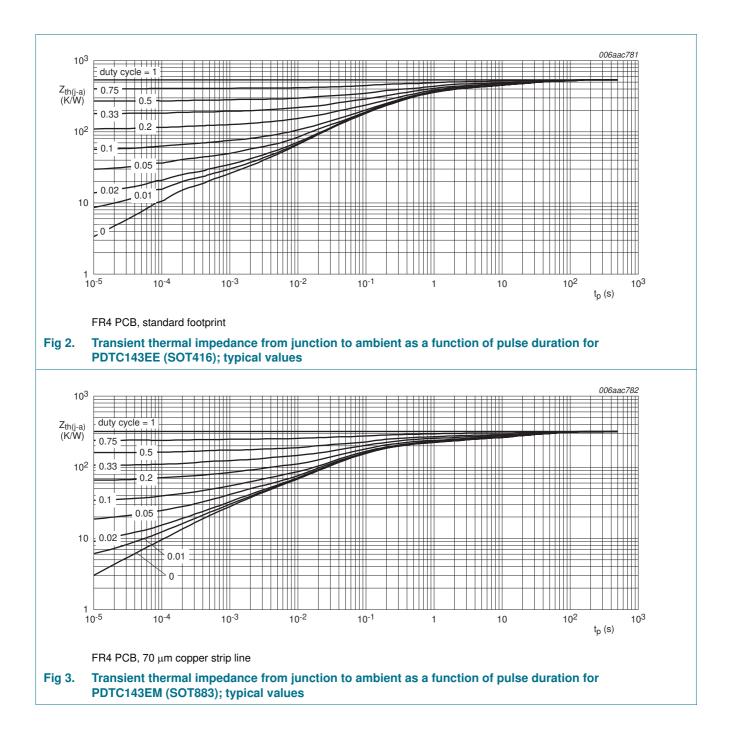
Table 7.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air				
	PDTC143EE (SOT416)		<u>[1][2]</u> _	-	830	K/W
	PDTC143EM (SOT883)		[2][3]	-	500	K/W
	PDTC143ET (SOT23)		<u>[1]</u> -	-	500	K/W
	PDTC143EU (SOT323)		<u>[1]</u> -	-	625	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

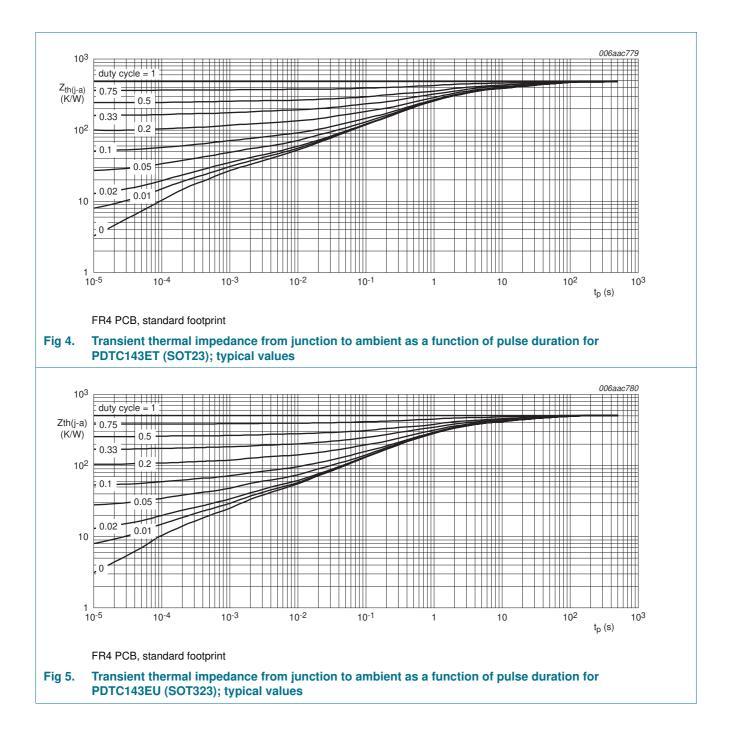
[2] Reflow soldering is the only recommended soldering method.

[3] Device mounted on an FR4 PCB with 70  $\mu$ m copper strip line, standard footprint.

# **PDTC143E series**



### **PDTC143E series**



NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 4.7 k $\Omega$ 

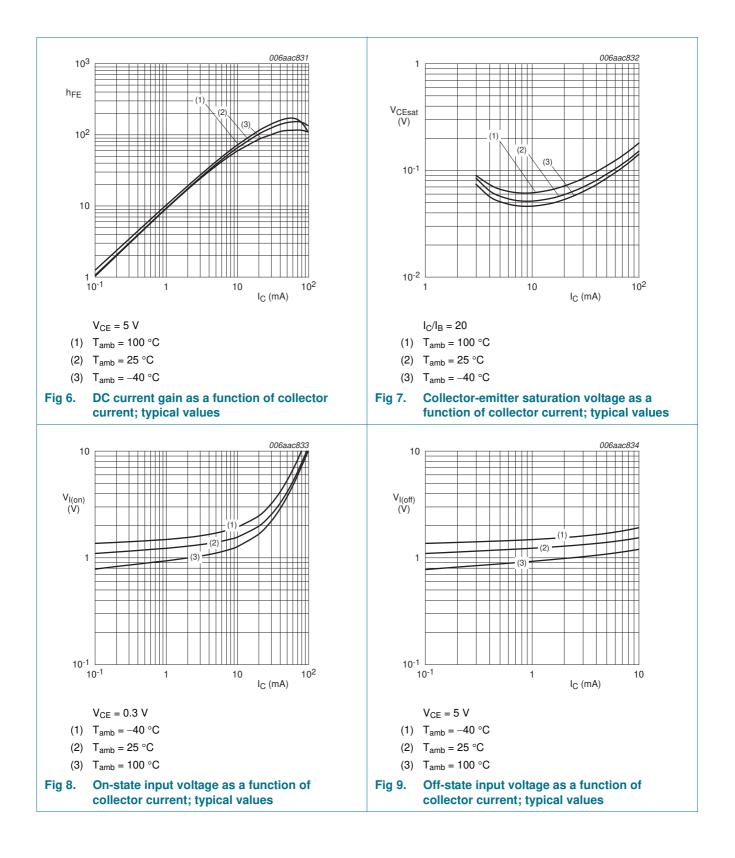
### 7. Characteristics

Symbol	Parameter	Conditions	Mi	n Typ	Max	Unit
I <sub>CBO</sub>	collector-base cut-off current	$V_{CB} = 50 \text{ V}; I_E = 0 \text{ A}$	-	-	100	nA
I <sub>CEO</sub>	collector-emitter	$V_{CE} = 30 \text{ V}; I_B = 0 \text{ A}$	-	-	1	μA
	cut-off current	$\label{eq:VCE} \begin{array}{l} V_{CE} = 30 \; V; \; I_{B} = 0 \; A; \\ T_{j} = 150 \; ^{\circ}C \end{array}$	-	-	5	μ <b>A</b>
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$	-	-	900	μ <b>A</b>
h <sub>FE</sub>	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 10 \text{ mA}$	30	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_{C} = 10 \text{ mA}; I_{B} = 0.5 \text{ mA}$	-	-	150	mV
V <sub>I(off)</sub>	off-state input voltage	$V_{CE}=5~V;~I_{C}=100~\mu A$	-	1.1	0.5	V
V <sub>I(on)</sub>	on-state input voltage	$V_{CE} = 0.3 \text{ V}; I_{C} = 20 \text{ mA}$	2.5	5 1.9	-	V
R1	bias resistor 1 (input)		3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio		0.8	3 1	1.2	
C <sub>c</sub>	collector capacitance	$\label{eq:VCB} \begin{array}{l} V_{CB} = 10 \text{ V};  \text{I}_{\text{E}} = \text{i}_{\text{e}} = 0 \text{ A}; \\ \text{f} = 1 \text{ MHz} \end{array}$	-	-	2.5	pF
f <sub>T</sub>	transition frequency	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 10 mA; f = 100 MHz	<u>[1]</u> -	230	-	MHz

[1] Characteristics of built-in transistor

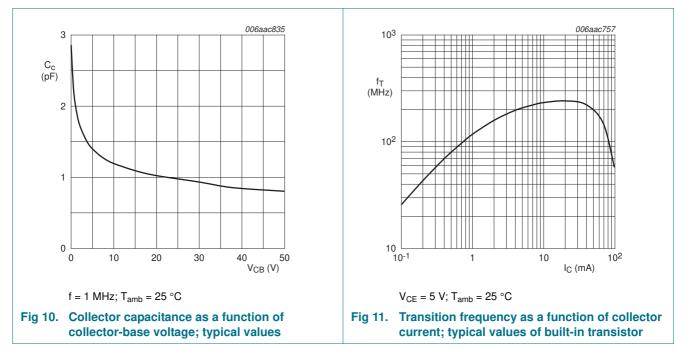
PDTC143E\_SER
Product data sheet

### **PDTC143E series**



# **PDTC143E series**

NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 4.7 k $\Omega$ 



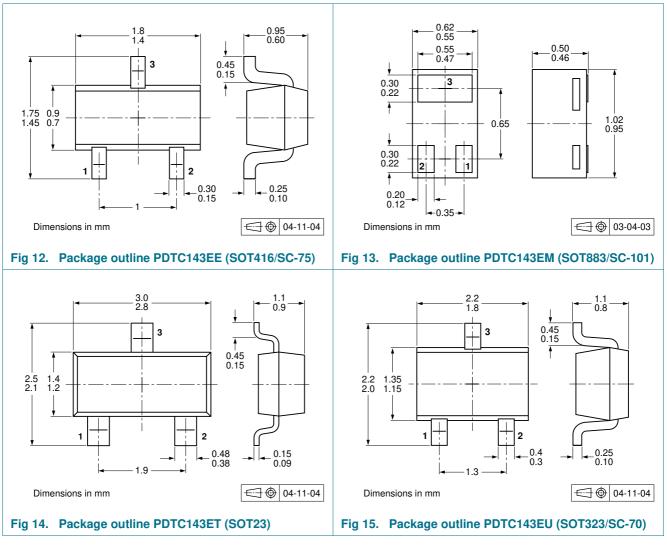
### 8. Test information

### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 4.7 k $\Omega$ 

#### **Package outline** 9.



### 10. Packing information

#### Table 9. **Packing methods**

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

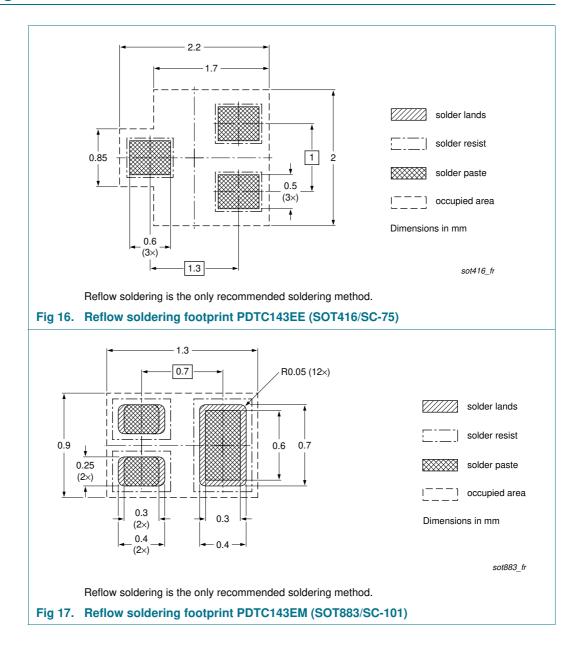
Type number	Package	Description	Packing quantity		
			3000	5000	10000
PDTC143EE	SOT416	4 mm pitch, 8 mm tape and reel	-115	-	-135
PDTC143EM	SOT883	2 mm pitch, 8 mm tape and reel	-	-	-315
PDTC143ET	SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-235
PDTC143EU	SOT323	4 mm pitch, 8 mm tape and reel	-115	-	-135

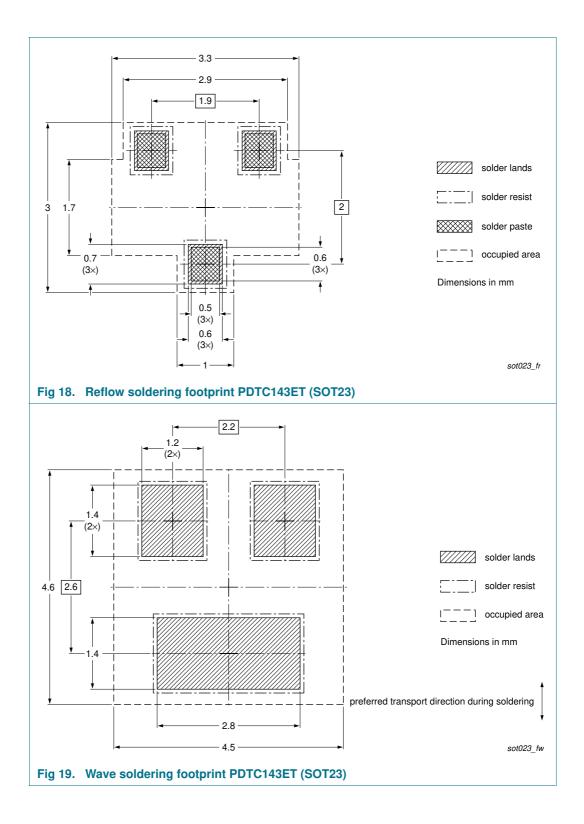
[1] For further information and the availability of packing methods, see Section 14.

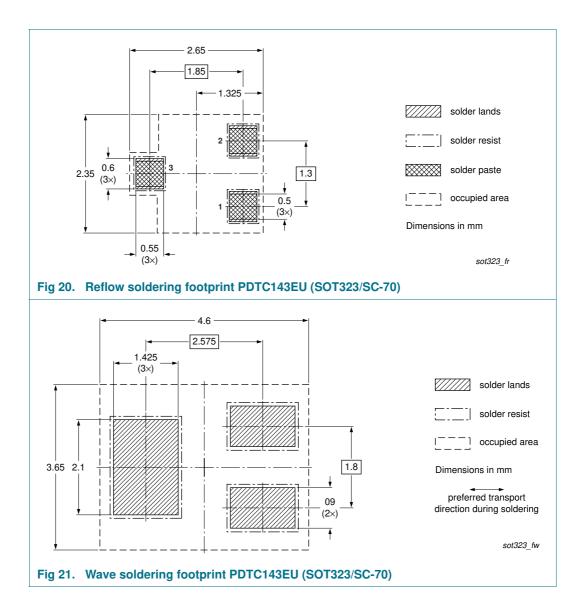
PDTC143E\_SER Product data sheet

NPN resistor-equipped transistors; R1 = 4.7 k\Omega, R2 = 4.7 k\Omega

### 11. Soldering







NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 4.7 k $\Omega$ 

### 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
PDTC143E_SER v.10	20111208	Product data sheet	-	PDTC143E_SERIES v.9		
Modifications:	<ul> <li>The format of this document has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li> </ul>					
	<ul> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>					
	<ul> <li>Type numbers PDTC143EEF, PDTC143EK and PDTC143ES removed.</li> </ul>					
	<ul> <li>Section 1 "F</li> </ul>	Product profile": updated				
	<u>Section 4 "Marking"</u> : updated					
	• Figure 1 to 11: added					
	<ul> <li><u>Section 6 "Thermal characteristics"</u>: updated</li> </ul>					
		<u>aracteristics"</u> : V <sub>i(on)</sub> redefine te input voltage, I <sub>CEO</sub> update		t voltage, $V_{i(off)}$ redefined to		
	<u>Section 8 "Test information"</u> : added					
	<ul> <li><u>Section 9 "Package outline"</u>: superseded by minimized package outline drawings</li> </ul>					
	<u>Section 10 "Packing information"</u> : added					
	<ul> <li>Section 11 "</li> </ul>	Soldering": added				
	<ul> <li>Section 13 '</li> </ul>	<u>'Legal information</u> ": updated				
PDTC143E_SERIES v.9	20040805	Product data sheet	-	PDTC143E_SERIES v.8		
PDTC143E_SERIES v.8	20040318	Product specification	-	PDTC143E_SERIES v.7		
PDTC143E_SERIES v.7	20040112	Product specification	-	PDTC143E_SERIES v.6		
PDTC143E_SERIES v.6	20030910	Product specification	-	PDTC143E_SERIES v.5		
PDTC143E_SERIES v.5	20030410	Product specification	-	_		

PDTC143E\_SER

### 13. Legal information

#### 13.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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Product data sheet

Rev. 10 — 8 December 2011

#### NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 4.7 k $\Omega$

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### PDTC143E\_SER Product data sheet

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### **PDTC143E series**

NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 4.7 k $\Omega$ 

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